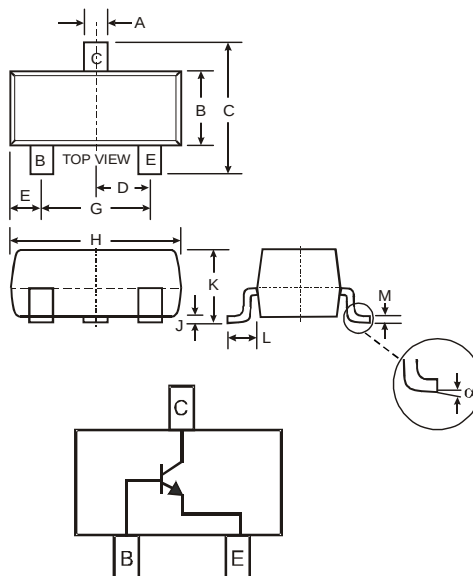


Features

- Epitaxial Planar Die Construction
- Complementary PNP Type Available (DP350T05)
- Ideal for Medium Power Amplification and Switching
- **Lead, Halogen and Antimony Free, RoHS Compliant "Green" Device (Notes 2, 3 and 4)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Mechanical Data

- Case: SOT-23
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminal Connections: See Diagram
- Terminals: Finish — Matte Tin Finish annealed over Alloy 42 leadframe. Solderable per MIL-STD-202, Method 208
- Marking Information: K3S, See Page 3
- Ordering & Date Code Information: See Page 3
- Weight: 0.008 grams (approximate)



SOT-23		
Dim	Min	Max
A	0.37	0.51
B	1.20	1.40
C	2.30	2.50
D	0.89	1.03
E	0.45	0.60
G	1.78	2.05
H	2.80	3.00
J	0.013	0.10
K	0.903	1.10
L	0.45	0.61
M	0.085	0.180
α	0°	8°
All Dimensions in mm		

Maximum Ratings @T_A = 25°C unless otherwise specified

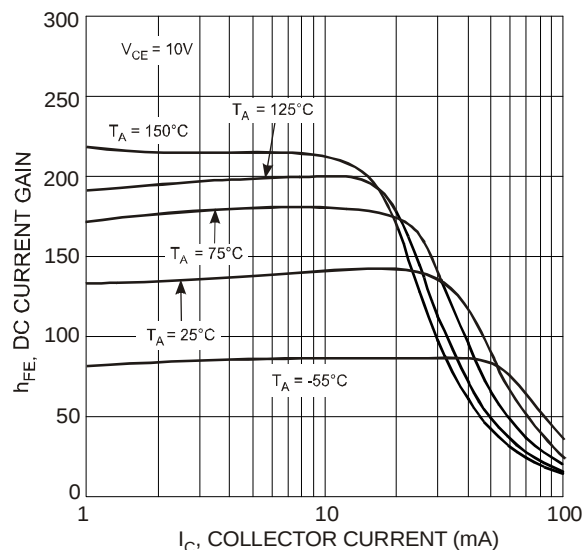
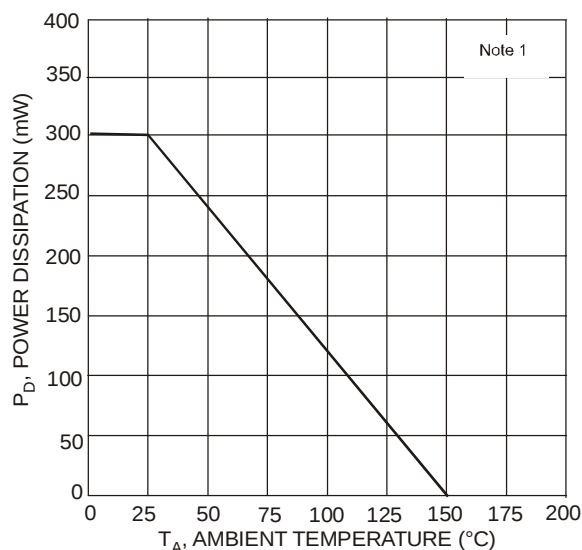
Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CB0}	350	V
Collector-Emitter Voltage	V _{CEO}	350	V
Emitter-Base Voltage	V _{EBO}	5.0	V
Continuous Collector Current	I _C	500	mA
Power Dissipation (Note 1)	P _D	300	mW
Thermal Resistance, Junction to Ambient (Note 1)	R _{θJA}	417	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

- Notes:
1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.
 2. No purposefully added lead. Halogen and Antimony Free.
 3. Diode's Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
 4. Product is manufactured with Green Molding Compound and does not contain Halogens or Sb₂O₃ Fire Retardants.

Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 5)					
Collector-Base Breakdown Voltage	V _{(BR)CBO}	350	—	V	I _C = 100μA, I _E = 0
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	350	—	V	I _C = 1.0mA, I _B = 0
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	5.0	—	V	I _E = 10μA, I _C = 0
Collector Cutoff Current	I _{CBO}	—	50	nA	V _{CB} = 250V, I _E = 0
Collector Cutoff Current	I _{EBO}	—	50	nA	V _{CE} = 5V, I _C = 0
ON CHARACTERISTICS (Note 5)					
DC Current Gain	h _{FE}	20	—	—	I _C = 1.0mA, V _{CE} = 10V
		30	—		I _C = 10mA, V _{CE} = 10V
		30	200		I _C = 30mA, V _{CE} = 10V
		20	200		I _C = 50mA, V _{CE} = 10V
		15	—		I _C = 100mA, V _{CE} = 10V
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	—	0.30	V	I _C = 10mA, I _B = 1.0mA
		—	0.35		I _C = 20mA, I _B = 2.0mA
		—	0.50		I _C = 30mA, I _B = 3.0mA
		—	1.0		I _C = 50mA, I _B = 5.0mA
Base-Emitter Saturation Voltage	V _{BE(SAT)}	—	0.75	V	I _C = 10mA, I _B = 1.0mA
		—	0.80		I _C = 20mA, I _B = 2.0mA
		—	0.90		I _C = 30mA, I _B = 3.0mA
Base-Emitter On Voltage	V _{BE(ON)}	—	2.0	V	I _C = 100mA, V _{CE} = 10V
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	C _{obo}	—	7.0	pF	V _{CB} = 20V, f = 1.0MHz, I _E = 0
Transition Frequency	f _T	50	—	MHz	V _{CE} = 10V, I _C = 20mA

Notes: 5. Short duration pulse test used to minimize self-heating effect.



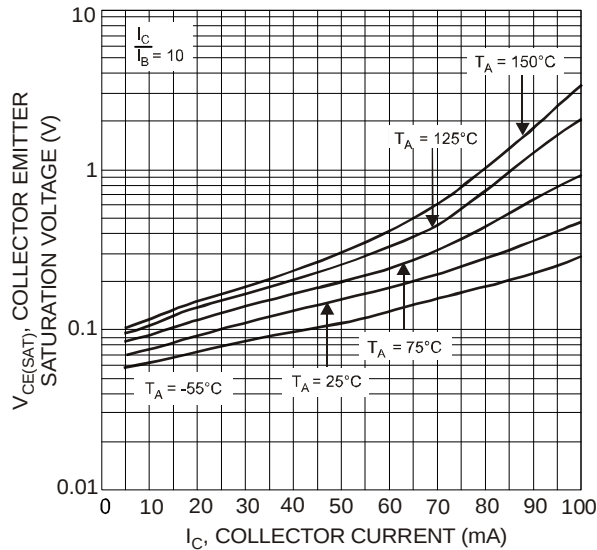


Fig. 3, Collector-Emitter Saturation Voltage vs. Collector Current

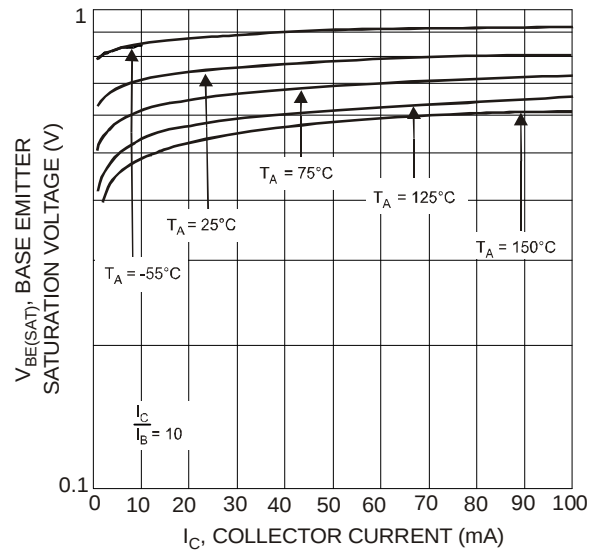


Fig. 4, Base-Emitter Saturation Voltage vs. Collector Current

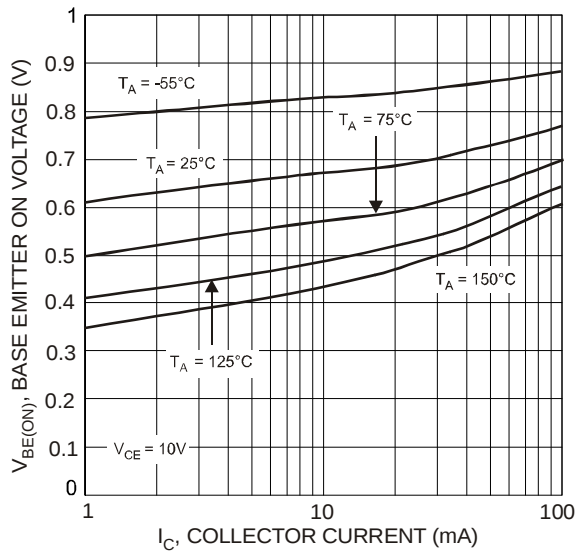


Fig. 5, Base-Emitter On Voltage vs. Collector Current

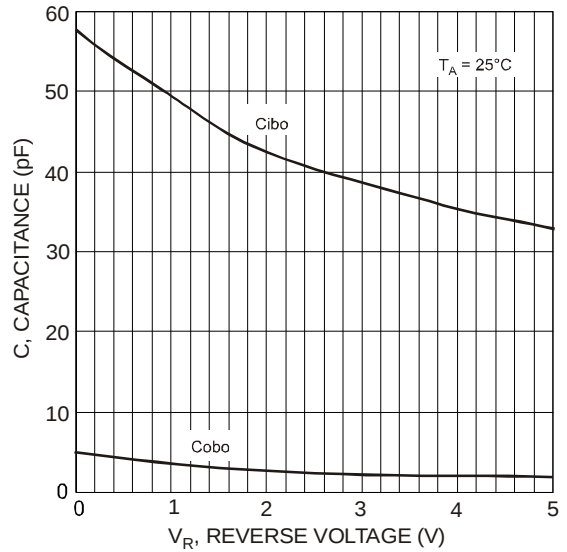


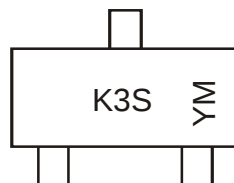
Fig. 6, Capacitance vs. Reverse Voltage

Ordering Information (Note 6)

Device	Packaging	Shipping
DN350T05-7	SOT-23	3000/Tape & Reel

Notes: 6. For packaging details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Marking Information



K3S = Product Type Marking Code
 YM = Date Code Marking
 Y = Year ex: S = 2005
 M = Month ex: 9 = September

Date Code Key

Year	2005	2006	2007	2008	2009	2010	2011	2012
Code	S	T	U	V	W	X	Y	Z

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

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